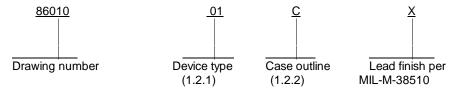
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REV SHEET			<u> </u>																
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OF SHEETS	-		SHE			1	2	3	4	5	6	7	8	9	10	11			
	Defense Electronics Supply Center Dayton, Ohio Original date		PREPARED BY Jeffery Tunstall					MILITARY DRAWING This drawing is available for use by all Departments an Agencies of the Department of Defense				and							
Dayton, Ohio			D A	CKED A Di Ce ROVE A Haucl	nzo D BY				MICROCIRCUITS, DIGITAL, HIGH-SPEED TITLE: CMOS DUAL UNBUFFERED HEX INVERTER MONOLITHIC SILICON										
25 January 1986				ZE 4			NT. NO 268		D W (G NO.				000	40				
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1. SCOPE

- 1.1 Scope. This drawing describes device requirements for class B microcircuits in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices".
 - 1.2 Part number. The complete part number shall be as shown in the following example:



1.2.1 <u>Device types</u>. The device types shall identify the circuit function as follows:

Device type	Generic number	<u>Circuit</u>
01	54HCU04	Unbuffered hex inverter

1.2.2 Case outlines. The case outlines shall be as designated in appendix C of MIL-M-38510, and as follows:

Outline letter	<u>Case outline</u>
С	D-1 (14-lead, 1/4" x 3/4"), dual-in-line package
2	C-2 (20-terminal, .350" x .350"), square chip carrier package

1.3 Absolute maximum ratings. 1/

Supply voltage range	0.5 V dc to +7.0 V dc
DC input voltage	0.5 V dc to V _{CC} +0.5 V dc
DC output voltage	0.5 V dc to V _{CC} +0.5 V dc
Clamp diode current ±	±20 mA
DC output current (per pin) ±	±25 mA
DC V _{CC} or GND current (per pin) ±	±50 mA
Storage temperature range	
Maximum power dissipation (P _D) 5	500 mW <u>2</u> /
Lead temperature (soldering, 10 seconds)+	+260° C
Thermal resistance, junction-to-case (θ_{IC}):	
Case C See MIL-M-38510, appendix C	
Case 2 6	60° C/W <u>3</u> /
Junction temperature (T _I)+	+175°C

MILITARY DRAWING	SIZE A	CODE IDENT. NO. 67268	86010
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL B	SHEET 2

 $[\]overline{1/}$ Unless otherwise specified, all voltages are referenced to ground. $\overline{2/}$ For $T_C = +100^{\circ}C$ to $+125^{\circ}C$, derate linearly at 12 mW/ $^{\circ}C$. $\overline{3/}$ When a thermal resistance for this case is specified in MIL-M-38510, appendix C, that value shall supersede the value specified herein.

1.4 Recommended operating conditions.

Supply voltage (V_{CC}) +2.0 V dc to +6.0 V dc Case operating temperature range (T_{C}) -55°C to +125°C Input rise or fall time: $V_{CC} = 2.0 \text{ V} \qquad 0 \text{ to } 1,000 \text{ ns}$ $V_{CC} = 4.5 \text{ V} \qquad 0 \text{ to } 500 \text{ ns}$

2. APPLICABLE DOCUMENTS

2.1 <u>Government specification and standard</u>. Unless otherwise specified, the following specification and standard, of the issue listed in that issue of the Department of Defense Index of Specifications and Standards specified in the solicitation, form a part of this drawing to the extent specified herein.

SPECIFICATION

MILITARY

MIL-M-38510

- Microcircuits, General Specification for.

STANDARD

MILITARY

MIL-STD-883 - Test Methods and Procedures for Microelectronics.

(Copies of the specification and standard required by manufacturers in connection with specific acquisition functions should be obtained from the contracting activity or as directed by the contracting activity.)

2.2 <u>Order of precedence</u>. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence.

3. REQUIREMENTS

- 3.1 <u>Item requirements</u>. The individual item requirements shall be in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices" and as specified herein.
- 3.2 <u>Design, construction, and physical dimensions</u>. The design, construction, and physical dimensions shall be as specified in MIL-M-38510 and herein.
 - 3.2.1 Terminal connections. The terminal connections shall be as specified on figure 1.
 - 3.2.2 Logic diagram. The logic diagram shall be as specified on figure 2.
 - 3.2.3 Case outlines. The case outlines shall be in accordance with 1.2.2 herein.
- 3.3 <u>Electrical performance characteristics</u>. Unless otherwise specified, the electrical performance characteristics are as specified in table I and apply over the full recommended case operating temperature range.
- 3.4 <u>Marking</u>. Marking shall be in accordance with MIL-STD-883 (see 3.1 herein). The part shall be marked with the part number listed in 1.2 herein. In addition, the manufacturer's part number may also be marked as listed in 6.4 herein.

MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	SIZE A	CODE IDENT. NO. 67268	86010
		REVISION LEVEL B	SHEET 3

I Act	Symbol	Conditions 1/		Group A	Limit	c	Unit
Test	Symbol	-55° C ≤ T _C ≤ +125°	С	subgroups	Min	Max	Offic
High-level output voltage	V _{OH}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $ I_O \le 20 \mu\text{A}$	V _{CC} = 2.0 V	1, 2, 3	1.8		V
			V _{CC} = 4.5 V		4.0		
			V _{CC} = 6.0 V		5.5		
		$ I_O \le 4.0 \text{ mA}$ $V_{IN} = V_{CC} \text{ or GND}$	V _{CC} = 4.5 V		3.7		
		$ I_O \le 5.2 \text{ mA}$ $V_{IN} = V_{CC} \text{ or GND}$	V _{CC} = 6.0 V		5.2		
Low-level output voltage	V _{OL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $ I_O \le 20 \mu\text{A}$	V _{CC} = 2.0 V	1, 2, 3		0.2	V
			V _{CC} = 4.5 V			0.5	
			V _{CC} = 6.0 V			0.5	
		$ I_O \le 4.0 \text{ mA}$ $V_{IN} = V_{CC} \text{ or GND}$	V _{CC} = 4.5 V			0.4	
		$ I_O \le 5.2 \text{ mA}$ $V_{IN} = V_{CC} \text{ or GND}$	V _{CC} = 6.0 V			0.4	
High-level input voltage	V _{IH}	2/	V _{CC} = 2.0 V	1, 2, 3	1.7		V
			V _{CC} = 4.5 V		3.6		
			V _{CC} = 6.0 V		4.8		
Low-level input voltage	V _{IL}	<u>2</u> /	V _{CC} = 2.0 V	1, 2, 3		0.3	V
			V _{CC} = 4.5 V			0.8	
			V _{CC} = 6.0 V			1.1	
Input capacitance	C _{IN}	V _{IN} = 0 V T _C = +25° C See 4.3.1c		4		15	pF

See footnotes at end of table.

MILITARY DRAWING	SIZE A	CODE IDENT. NO. 67268	86010
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL B	SHEET 4

Test	Symbol	Conditions 1/		Group A	Limit	rc	Unit
1 631	Зуппол	-55° C ≤ T _C ≤ +125° C		subgroups	Min	Max	Offic
Quiescent current	I _{CC}	$V_{CC} = 6.0 \ V_{IN} = V_{CC} \text{ or GND}$		1, 2, 3		40	μA
Input leakage current	I _{IN}	$V_{CC} = 6.0 \ V_{IN} = V_{CC}$ or	GND	1, 2, 3		±1	μA
Functional tests		See 4.3.1d	See 4.3.1d				
Propagation delay time A to Y	t _{PHL}	T _C = +25° C C _L = 50 pF ±10%	V _{CC} = 2.0 V	9		80	ns
<u>3</u> /			V _{CC} = 4.5 V			16	
		V _{CC} = 6.0 V			14		
		T _C = -55° C, +125° C C _L = 50 pF ±10%	V _{CC} = 2.0 V	10, 11		120	ns
		See figure 3	V _{CC} = 4.5 V			24	
			V _{CC} = 6.0 V			20	
Transition time	t _{TLH}	T _C = +25° C C _L = 50 pF ±10%	V _{CC} = 2.0 V	9		75	ns
<u>4</u> /	1112	See figure 3	V _{CC} = 4.5 V			15	
			V _{CC} = 6.0 V			13	
		T _C = -55° C, +125° C C _L = 50 pF ±10%	V _{CC} = 2.0 V	10, 11		110	ns
		See figure 3	V _{CC} = 4.5 V			22	
			V _{CC} = 6.0 V			19	

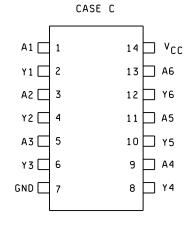
^{1/} For a power supply of 5 V ±10 percent the worst case output voltages (V_{OH} and V_{OL}) occur for HC at 4.5 V. Thus, the 4.5 V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC} = 5.5 V and 4.5 V, respectively. (The V_{IH} value at 5.5 V is 3.85 V). The worst case leakage current (I_{IN} , I_{CC} , and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0 V values should be used. Power dissipation capacitance (I_{CD}), typically 40 pF, determines the no load dynamic power consumption, I_{CC} = I_{CC} I_{CC} = I_{CC} I_{CC} and the no load dynamic current consumption, I_{CC} = I_{CC} I_{CC} f+ I_{CC} .

2/ Test not required if applied as a forcing function for I_{CC} or I_{CC} and the specified parameters.

 $\underline{4}/$ Transition time (t_{TLH}, t_{THL}), if not tested, shall be guaranteed to the specified parameters.

MILITARY DRAWING	SIZE A	CODE IDENT. NO. 67268	86010
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL B	SHEET 5

parameters.



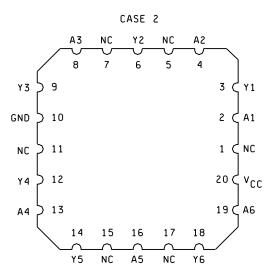


FIGURE 1. Terminal connections (top view).

MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	SIZE A	CODE IDENT. NO. 67268	86010
		REVISION LEVEL B	SHEET 6

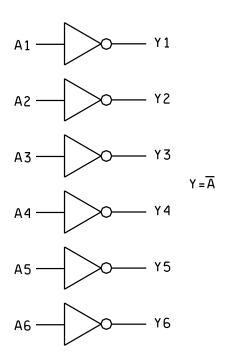
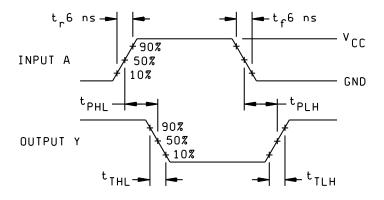


FIGURE 2. Logic diagram.

MILITARY DRAWING
DEFENSE ELECTRONICS SUPPLY CENTER
DAYTON, OHIO 45444

SIZE
A
67268

REVISION LEVEL
B
7



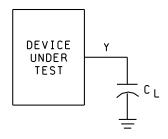


FIGURE 3. Switching waveforms.

MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	SIZE A	CODE IDENT. NO. 67268	86010
		REVISION LEVEL B	SHEET 8

- 3.5 <u>Certificate of compliance</u>. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in 6.4. The certificate of compliance submitted to DESC-ECS prior to listing as an approved source of supply shall state that the manufacturer's product meets the requirements of MIL-STD-883 (see 3.1 herein) and the requirements herein.
- 3.6 <u>Certificate of conformance</u>. A certificate of conformance as required in MIL-STD-883 (see 3.1 herein) shall be provided with each lot of microcircuits delivered to this drawing.
- 3.7 <u>Notification of change</u>. Notification of change to DESC-ECS shall be required in accordance with MIL-STD-883 (see 3.1 herein).
- 3.8 <u>Verification and review</u>. DESC, DESC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.
 - 4. QUALITY ASSURANCE PROVISIONS
- 4.1 <u>Sampling and inspection</u>. Sampling and inspection procedures shall be in accordance with section 4 of MIL-M-38510 to the extent specified in MIL-STD-883 (see 3.1 herein).
- 4.2 <u>Screening</u>. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:
 - a. Burn-in test (method 1015 of MIL-STD-883).
 - (1) Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.5 herein).
 - (2) $T_A = +125^{\circ} C$, minimum.
 - b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.
- 4.3 <u>Quality conformance inspection</u>. Quality conformance inspection shall be in accordance with method 5005 of MIL-STD-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.
 - 4.3.1 Group A inspection.
 - a. Tests shall be as specified in table II herein.
 - b. Subgroups 5, 6, and 8 in table I, method 5005 of MIL-STD-883 shall be omitted.
 - c. Subgroup 4 (C_{IN} measurement) shall be measured only for the initial test and after process or design changes which may affect input capacitance.
 - d. Subgroup 7 tests shall verify the truth table.

MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	SIZE A	CODE IDENT. NO. 67268	86010
		REVISION LEVEL B	SHEET 9

TABLE II. Electrical test requirements.

MIL-STD-883 test requirements	Subgroups (per method 5005, table I)
Interim electrical parameters (method 5004)	
Final electrical test parameters (method 5004)	1*, 2, 9
Group A test requirements (method 5005)	1, 2, 3, 7, 9, 10, 11**
Groups C and D end-point electrical parameters (method 5005)	1, 2, 3
Additional electrical subgroups for group C periodic inspections	

^{*} PDA applies to subgroup 1.

4.3.2 Groups C and D inspections.

- a. End-point electrical parameters shall be as specified in table II herein.
- b. Steady-state life test (method 1005 of MIL-STD-883) conditions:
 - (1) Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.5 herein).
 - (2) $T_A = +125^{\circ} C$, minimum.
 - (3) Test duration: 1,000 hours, except as permitted by appendix B of MIL-M-38510 and method 1005 of MIL-STD-883.
- 5. PACKAGING
- 5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-M-38510.
- 6. NOTES
- 6.1 <u>Intended use</u>. Microcircuits conforming to this drawing are intended for use when military specifications do not exist and qualified military devices that will perform the required function are not available for OEM application. When a military specification exists and the product covered by this drawing has been qualified for listing on QPL-38510, the device specified herein will be inactivated and will not be used for new design. The QPL-38510 product shall be the preferred item for all applications.
- 6.2 <u>Replaceability</u>. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.
- 6.3 <u>Comments</u>. Comments on this drawing should be directed to DESC-ECS, Dayton, Ohio 45444, or telephone 513-296-5375.

MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	SIZE A	CODE IDENT. NO. 67268	86010
		REVISION LEVEL B	SHEET 10

^{**} Subgroups 10 and 11, if not tested, shall be guaranteed to the specified limits in table I.

6.4 <u>Approved sources of supply</u>. Approved sources of supply are listed herein. Additional sources will be added as they become available. The vendors listed herein have agreed to this drawing and a certificate of compliance (see 3.5 herein) has been submitted to DESC-ECS.

Military drawing part number	Vendor CAGE number	Vendor similar part number <u>1</u> /
8601001CX	27014 04713 18714 01295	DM54HCU04J/883B 54HCU04/BCAJC CD54HCU04F/3A SNJ54HCU04J
86010012X	04713 02195	54HCU04M/B2CJC SNJ54HCU04FK

1/ <u>Caution</u>. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

Vendor CAGE <u>number</u>	Vendor name and address
27014	National Semiconductor P.O. Box 58090 Santa Clara, CA 95052-8090
04713	Motorola, Incorporated 7402 S. Price Road Tempe, AZ 85283
18714	RCA Corporation Route 202 Somerville, NJ 08876
01295	Texas Instruments, Incorporated P.O. Box 6448 Midland, TX 79701

MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	SIZE A	CODE IDENT. NO. 67268	86010
		REVISION LEVEL B	SHEET 11